

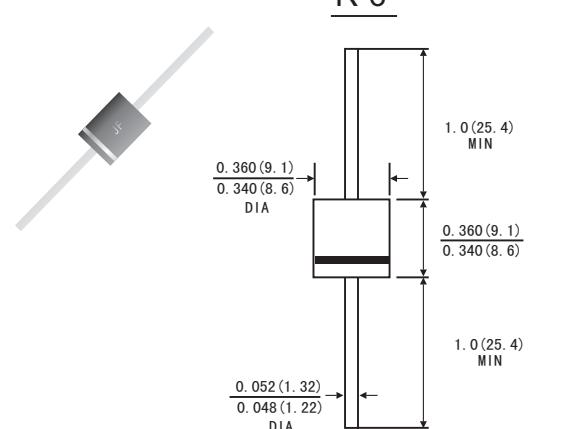


12SQ045

SCHOTTKY BARRIER RECTIFIER
Reverse Voltage - 45 Volts
Forward Current - 12.0 Amperes

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters,
free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2011/65/EU



Dimensions in inches and (millimeters)

MECHANICAL DATA

- Case: R-6 molded plastic body
- Terminals: Plated axial lead, solderable per MIL-STD-750,method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

	Symbols	12SQ045	Units
Maximum repetitive peak reverse voltage	V _{RRM}	45	Volts
Maximum RMS voltage	V _{RMS}	32	Volts
Maximum DC blocking voltage	V _{DC}	45	Volts
Maximum average forward rectified current 0.375"(9.5mm) lead length(see fig.1)	I _(AV)	12.0	Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated T _J)	I _{FSM}	275	Amps
Maximum instantaneous forward voltage at 12.0 A(Note 1)	V _F	0.55	Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	I _R	0.2 50	mA
Typical junction capacitance(Note 3)	C _J	400	pF
Typical thermal resistance (Note 2)	R _{θJC}	2.5	°C/W
Operating junction temperature range at reduced reverse voltage V _R <=80%V _{RRM} V _R <=50%V _{RRM} in DC forward model	T _J	-65 to +150 -65 to +175 -65 to +200	°C
Storage temperature range	T _{STG}	-65 to +200	°C

- Notes: 1.Pulse test: 300μs pulse width,1% duty cycle
 2.Thermal resistance from junction to case
 3.Measured at 1MHz and reverse voltage of 4.0 volts

RATINGS AND CHARACTERISTIC CURVES 12SQ045

FIG.1-FORWARD CURRENT DERATING CURVE

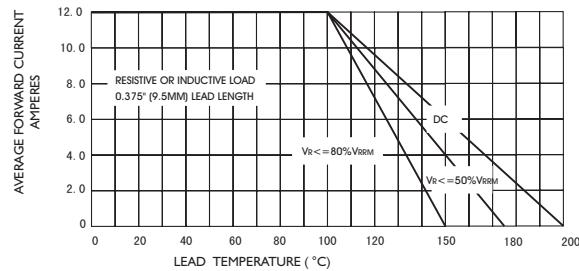


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

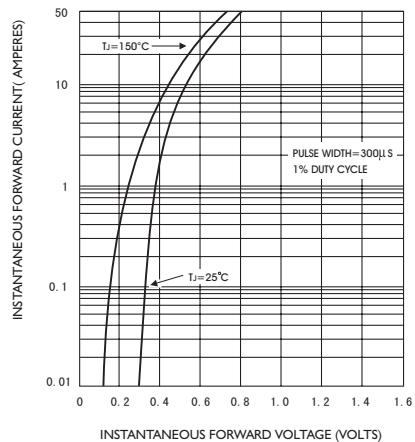
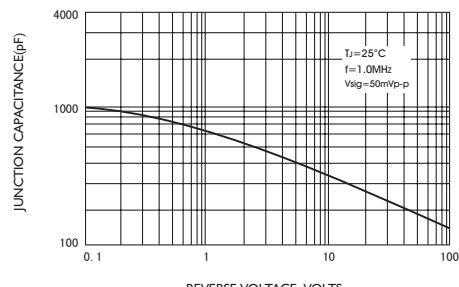


FIG.5-TYPICAL JUNCTION CAPACITANCE



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FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

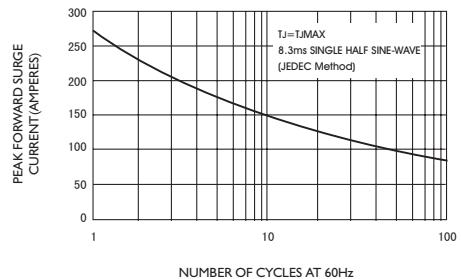


FIG.4-TYPICAL REVERSE CHARACTERISTICS

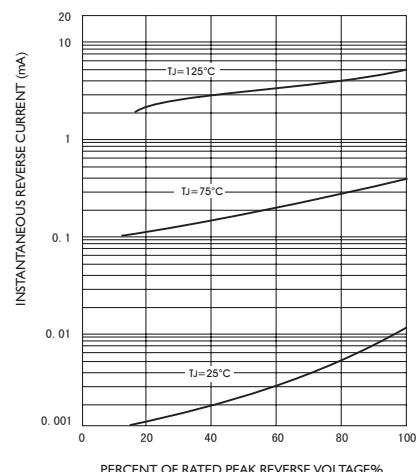
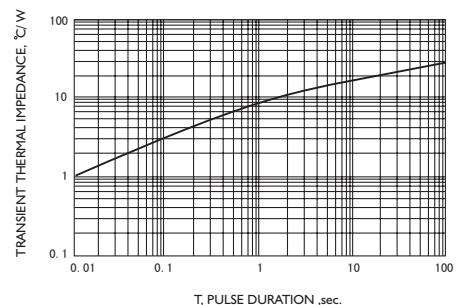


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE



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